

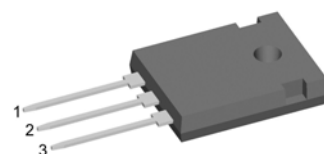
HiPerFRED²

$$\begin{aligned}
 V_{RRM} &= 300\text{ V} \\
 I_{FAV} &= 2 \times 15\text{ A} \\
 t_{rr} &= 35\text{ ns}
 \end{aligned}$$

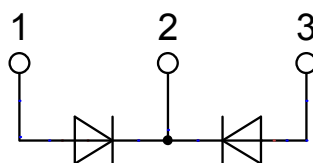
High Performance Fast Recovery Diode
 Low Loss and Soft Recovery
 Common Cathode

Part number

DPG30C300HB



Backside: cathode

**Features / Advantages:**

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

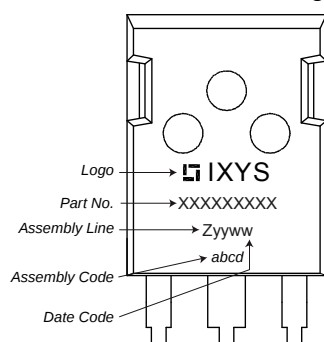
Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Fast Diode				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse blocking voltage	T _{VJ} = 25°C				300	V
V _{RRM}	max. repetitive reverse blocking voltage	T _{VJ} = 25°C				300	V
I _R	reverse current, drain current	V _R = 300 V	T _{VJ} = 25°C			1	μA
		V _R = 300 V	T _{VJ} = 150°C			0.08	mA
V _F	forward voltage drop	I _F = 15 A	T _{VJ} = 25°C			1.25	V
		I _F = 30 A				1.50	V
		I _F = 15 A	T _{VJ} = 150°C			1.00	V
		I _F = 30 A				1.27	V
I _{FAV}	average forward current	T _C = 145°C rectangular d = 0.5	T _{VJ} = 175°C			15	A
V _{F0}	threshold voltage	} for power loss calculation only		T _{VJ} = 175°C		0.69	V
r _F	slope resistance					17.3	mΩ
R _{thJC}	thermal resistance junction to case					1.7	K/W
R _{thCH}	thermal resistance case to heatsink				0.25		K/W
P _{tot}	total power dissipation	T _C = 25°C				90	W
I _{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine; V _R = 0 V		T _{VJ} = 45°C		240	A
C _J	junction capacitance	V _R = 150 V f = 1 MHz		T _{VJ} = 25°C	20		pF
I _{RM}	max. reverse recovery current	} I _F = 15 A; V _R = 200 V -di _F /dt = 200 A/μs		T _{VJ} = 25°C	3		A
				T _{VJ} = 125°C	6.5		A
t _{rr}	reverse recovery time			T _{VJ} = 25°C	35		ns
				T _{VJ} = 125°C	55		ns

Package TO-247			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal ¹⁾			50	A
T_{VJ}	virtual junction temperature		-55		175	°C
T_{op}	operation temperature		-55		150	°C
T_{stg}	storage temperature		-55		150	°C
Weight				6		g
M_D	mounting torque		0.8		1.2	Nm
F_C	mounting force with clip		20		120	N

Product Marking



Part number

D = Diode
 P = HiPerFRED
 G = extreme fast
 30 = Current Rating [A]
 C = Common Cathode
 300 = Reverse Voltage [V]
 HB = TO-247AD (3)

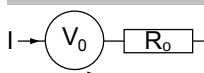
Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DPG30C300HB	DPG30C300HB	Tube	30	502567

Similar Part	Package	Voltage class
DPG30C300PB	TO-220AB (3)	300
DPG30C300PC	TO-263AB (D2Pak) (2)	300

Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 175\text{ °C}$



Fast Diode

$V_{0\max}$ threshold voltage

0.69

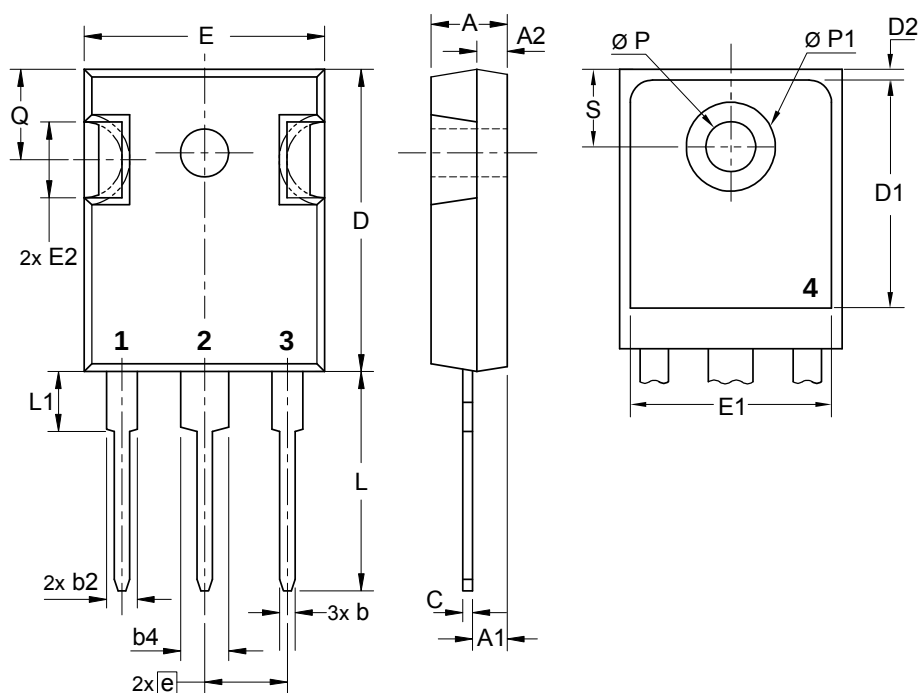
V

$R_{0\max}$ slope resistance *

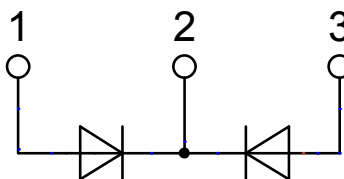
14.7

mΩ

Outlines TO-247



Sym.	Inches		Millimeter	
	min.	max.	min.	max.
A	0.185	0.209	4.70	5.30
A1	0.087	0.102	2.21	2.59
A2	0.059	0.098	1.50	2.49
D	0.819	0.845	20.79	21.45
E	0.610	0.640	15.48	16.24
E2	0.170	0.216	4.31	5.48
e	0.215	BSC	5.46	BSC
L	0.780	0.800	19.80	20.30
L1	-	0.177	-	4.49
Ø P	0.140	0.144	3.55	3.65
Q	0.212	0.244	5.38	6.19
S	0.242	BSC	6.14	BSC
b	0.039	0.055	0.99	1.40
b2	0.065	0.094	1.65	2.39
b4	0.102	0.135	2.59	3.43
c	0.015	0.035	0.38	0.89
D1	0.515	-	13.07	-
D2	0.020	0.053	0.51	1.35
E1	0.530	-	13.45	-
Ø P1	-	0.29	-	7.39



Fast Diode

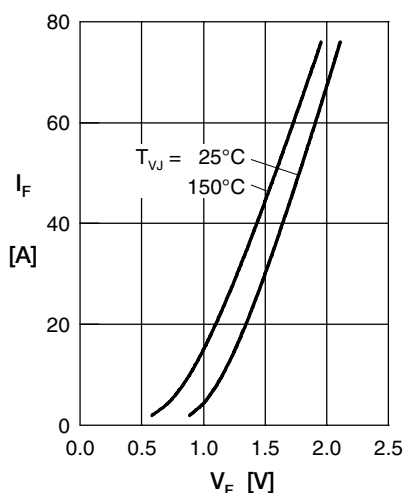


Fig. 1 Forward current I_F versus V_F

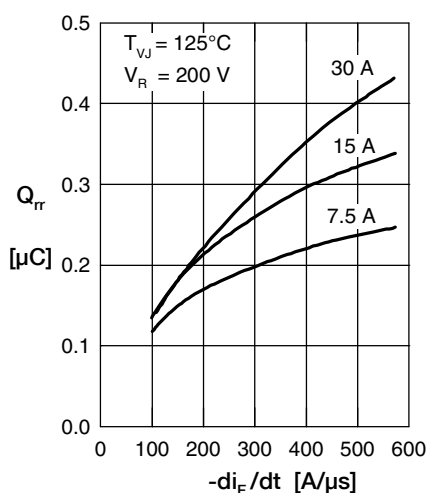


Fig. 2 Typ. reverse recov. charge Q_{rr} versus $-di_F/dt$

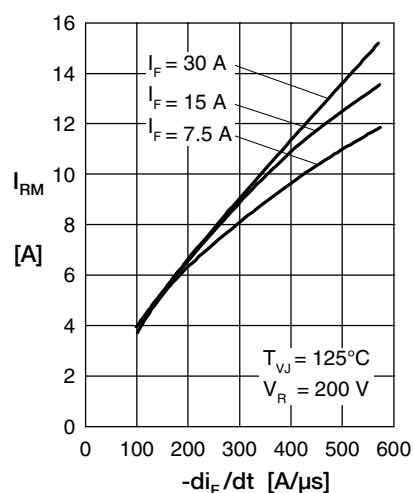


Fig. 3 Typ. peak reverse current I_{RM} versus $-di_F/dt$

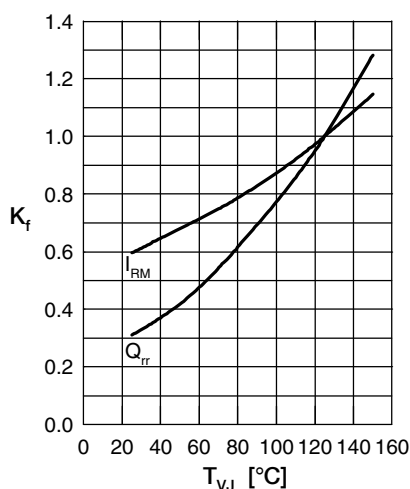


Fig. 4 Typ. dynamic parameters Q_{rr} , I_{RM} versus T_{VJ}

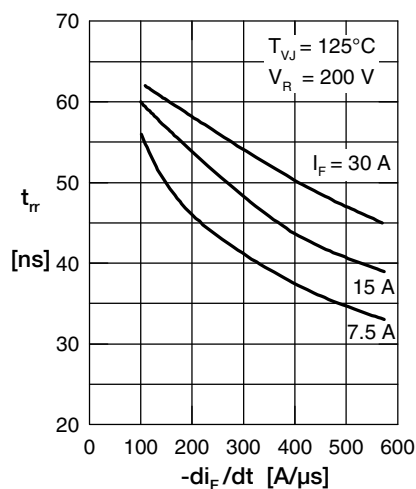


Fig. 5 Typ. recovery time t_{rr} versus $-di_F/dt$

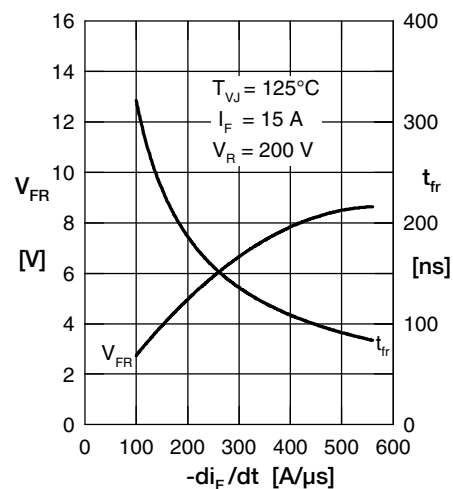


Fig. 6 Typ. peak forward voltage V_{FR} and t_{fr} versus di_F/dt

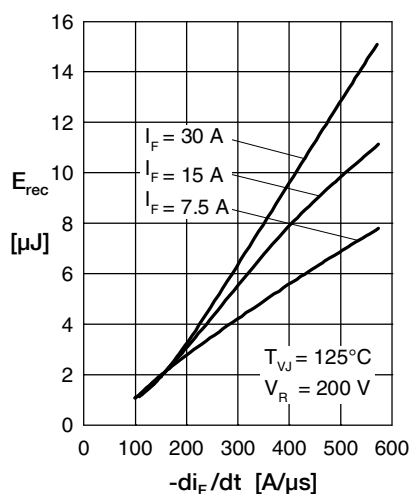


Fig. 7 Typ. recovery energy E_{rec} versus $-di_F/dt$

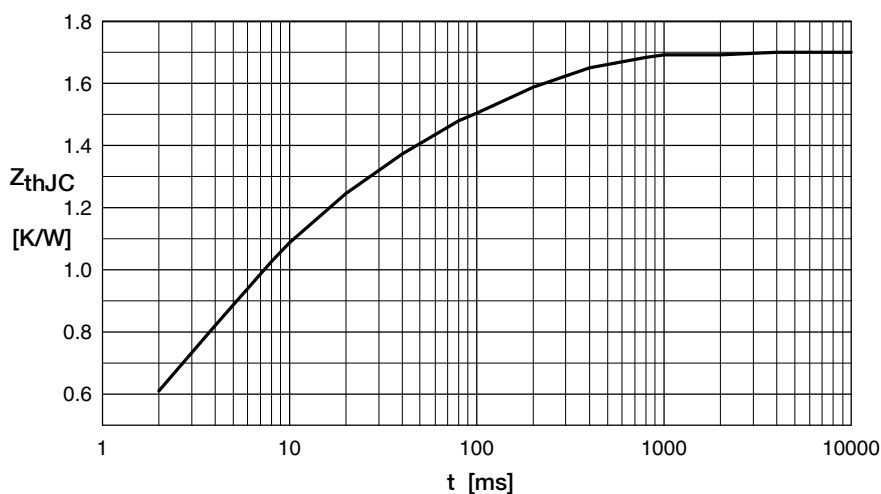


Fig. 8 Transient thermal resistance junction to case

AMEYA360

Components Supply Platform

Authorized Distribution Brand :



Website :

Welcome to visit www.ameya360.com

Contact Us :

➤ Address :

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd
Minhang District, Shanghai , China

➤ Sales :

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

➤ Customer Service :

Email service@ameya360.com

➤ Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com